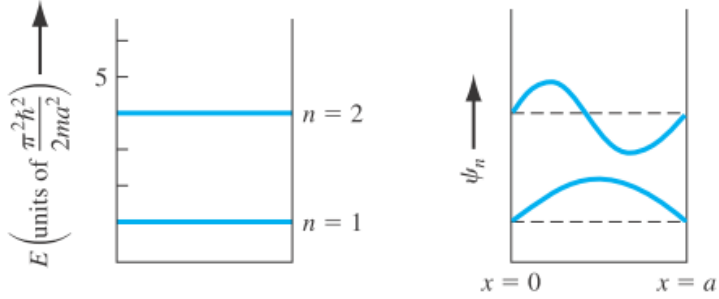


1.A. (8 points)

$$\psi(x) = \sqrt{\frac{2}{a}} \sin\left(\frac{n\pi x}{a}\right)$$

$$E_n(x) = \frac{\hbar^2 n^2 \pi^2}{2ma^2}$$



1.B. (8 points).

$$g_E(E) dE = g_k(k) dk$$

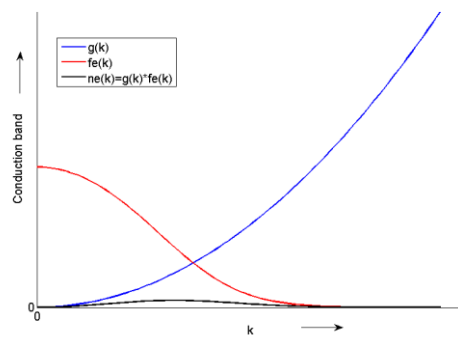
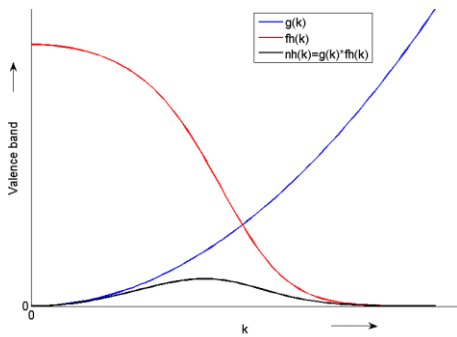
$$g_k(k) = \frac{k^2}{\pi^3}$$

Assume conventional parabolic band structure:

$$E = E_C + \frac{\hbar^2 k^2}{2m^*} \quad E = E_v - \frac{\hbar^2 k^2}{2m^*}$$

$$\text{Fermi-Dirac of electrons in conduction band : } f_e = \frac{1}{1 + \exp\left(\frac{E - E_F}{k_B T}\right)} = \frac{1}{1 + \exp\left(\frac{E_C + \frac{\hbar^2 k^2}{2m^*} - E_F}{k_B T}\right)}$$

$$\text{Fermi-Dirac of holes in valence band : } f_h = 1 - f_e = 1 - \frac{1}{1 + \exp\left(\frac{E_v - \frac{\hbar^2 k^2}{2m^*} - E_F}{k_B T}\right)}$$



Question 2. (15 points)

$$J_{diff}(x) = -eD_p \frac{dp}{dx} = -\frac{eD_p}{L} \left( 2 \times 10^{16} \left( 1 + \frac{x}{L} \right) \right)$$
$$J_{diff}(-6) = -\frac{(1.6 \times 10^{-19})(10)}{12 \times 10^{-4}} \left( 2 \times 10^{16} \left( 1 - \frac{6}{12} \right) \right) = \underline{-13.33 \text{ A/cm}^2}$$

Question 3. (16 points)

$$E_{Fi} - E_F = kT \ln \left( \frac{N_a}{n_i} \right) = 0.0259 \ln \left( \frac{5 \times 10^{15}}{1.5 \times 10^{10}} \right) = \underline{0.33 \text{ eV}}$$
$$p = N_a + 0.1N_a = 1.1N_a$$
$$n = n_0 + 0.1N_a \approx 0.1N_a$$
$$E_{Fn} - E_{Fi} = kT \ln \left( \frac{n}{n_i} \right) = 0.0259 \ln \left( \frac{0.1 \times 5 \times 10^{15}}{1.5 \times 10^{10}} \right) = \underline{0.27 \text{ eV}}$$
$$E_{Fi} - E_{Fp} = kT \ln \left( \frac{p}{n_i} \right) = 0.0259 \ln \left( \frac{1.1 \times 5 \times 10^{15}}{1.5 \times 10^{10}} \right) = \underline{0.33 \text{ eV}}$$

Question 4. (15 points)

$$V_B = \frac{\varepsilon E_{crit}^2}{2eN_B} = \frac{12.11 \times 8.85 \times 10^{-14} \times (4 \times 10^5)^2}{2 \times 1.6 \times 10^{-19} \times 2 \times 10^{16}} = 26.79V$$

Question 5.

5.A. (10 points)

(a)(5 points)

$$\begin{aligned}J_S &= en_i^2 \left( \frac{1}{N_a} \sqrt{\frac{D_n}{\tau_{n0}}} + \frac{1}{N_d} \sqrt{\frac{D_p}{\tau_{p0}}} \right) \\&= (1.6 \times 10^{-19}) \times (2.4 \times 10^{13})^2 \times \left( \frac{1}{4 \times 10^{15}} \sqrt{\frac{90}{2 \times 10^{-6}}} + \frac{1}{2 \times 10^{17}} \sqrt{\frac{48}{2 \times 10^{-6}}} \right) = 1.568 \times 10^{-4} \text{ A/cm}^2 \\J_D &= J_S \cdot \left[ \exp\left(\frac{eV_a}{kT}\right) - 1 \right] \\&= J_S \cdot \left( \exp\left(\frac{0.25}{0.0259}\right) - 1 \right) \\&= 2.44 \text{ A/cm}^2 \\J &= J_D \cdot A = 2.44 \times 10^{-4} \text{ A} = 0.244 \text{ mA}\end{aligned}$$

(b)(5 points)

$$\begin{aligned}V_{bi} &= V_T \times \ln\left(\frac{N_a N_d}{n_i^2}\right) = 0.0259 \times \ln\left(\frac{4 \times 10^{15} \times 2 \times 10^{17}}{(2.4 \times 10^{13})^2}\right) = 0.366 \text{ V} \\W &= \left\{ \frac{2\epsilon_S (V_{bi} + V_R)}{e} \cdot \frac{N_a + N_d}{N_a \cdot N_d} \right\}^{1/2} = 5.273 \times 10^{-5} \text{ cm} \\J_{gen} &= \frac{en_i W}{2\tau_0} = 5.062 \times 10^{-5} \text{ A/cm}^2 \\J_R &= J_{gen} + J_S = 2.074 \times 10^{-4} \text{ A/cm}^2 \\J &= J_R \cdot A = 2.074 \times 10^{-8} \text{ A} \approx 0 \text{ A, almost no current for reverse-biased voltage}\end{aligned}$$

5.B. (10 points)

The minority carrier electron distribution changes linearly with distance.

The minority carrier electron current density  $J_n = \frac{eD_n n_{p0}}{W_p} \left[ \exp\left(\frac{eV_a}{kT}\right) - 1 \right]$

Question 6. (18 points)

6.A. (8 points)

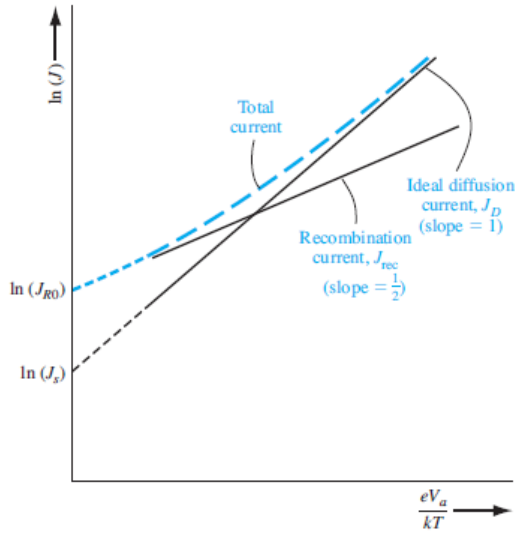


Figure 8.16 | Ideal diffusion, recombination, and total current in a forward-biased pn junction.

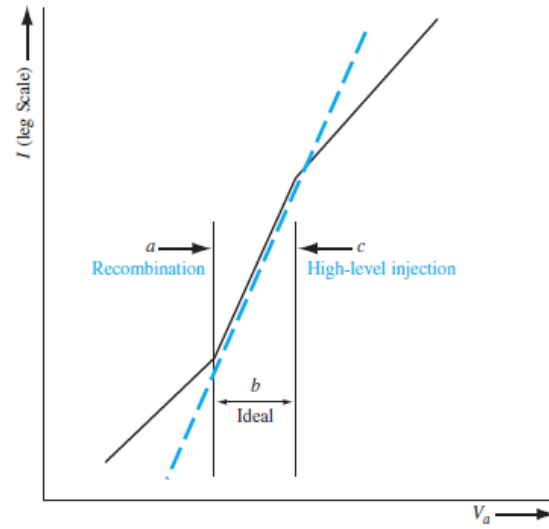


Figure 8.17 | Forward-bias current versus voltage from low forward bias to high forward bias.

6.B. (10 points)

$$V_{bi} = V_T \times \ln\left(\frac{N_a N_d}{n_i^2}\right) = 0.0259 \times \ln\left(\frac{4 \times 10^{16} \times 4 \times 10^{16}}{(1.5 \times 10^{10})^2}\right) = 0.766V$$

$$J_s = en_i \left( \frac{1}{N_a} \sqrt{\frac{D_n}{\tau_{n0}}} + \frac{1}{N_d} \sqrt{\frac{D_p}{\tau_{p0}}} \right) = 2.686 \times 10^{-11} A/cm^2$$

$$J_D = J_s \cdot \exp\left(\frac{eV_a}{kT}\right)$$

$$J_{rec} = \frac{en_i W}{2\tau_0} \cdot \exp\left(\frac{eV_a}{2kT}\right), \text{ where } W = \left[ \frac{2\epsilon_S (V_{bi} - V_a)}{e} \cdot \frac{N_a + N_d}{N_a \cdot N_d} \right]^{1/2}$$

let  $J_D = J_{rec}$  (solved graphically or by approximation)

$$\Rightarrow V_a = 0.454V$$